

Product Features

- PI74ALVCHR162524 is designed for low voltage operation
- $V_{CC} = 2.3V$ to $3.6V$
- Hysteresis on all inputs
- Typical V_{OLP} (Output Ground Bounce) $< 0.8V$ at $V_{CC} = 3.3V, T_A = 25^\circ C$
- Typical V_{OHV} (Output V_{OH} Undershoot) $< 2.0V$ at $V_{CC} = 3.3V, T_A = 25^\circ C$
- Bus Hold retains last active bus state during 3-STATE eliminating the need for external pullup resistors
- Industrial operation at $-40^\circ C$ to $+85^\circ C$
- Packages available:
 - 48-pin 240 mil wide plastic TSSOP (A48)
 - 48-pin 300 mil wide plastic SSOP (V48)

Product Description

Pericom Semiconductor’s PI74ALVCH series of logic circuits are produced in the Company’s advanced 0.5 micron CMOS technology, achieving industry leading speed.

The PI74ALVCHR162524 data flow in each direction is controlled by output-enable (\overline{OEAB} and \overline{OEBA}) and clock-enable ($\overline{CLKENBA}$) inputs. For the A-to-B data flow, the data flows through a single register. The B-to-A data can flow through a four-stage pipeline register path, or through a single register path, depending on the state of the select (\overline{SEL}) input.

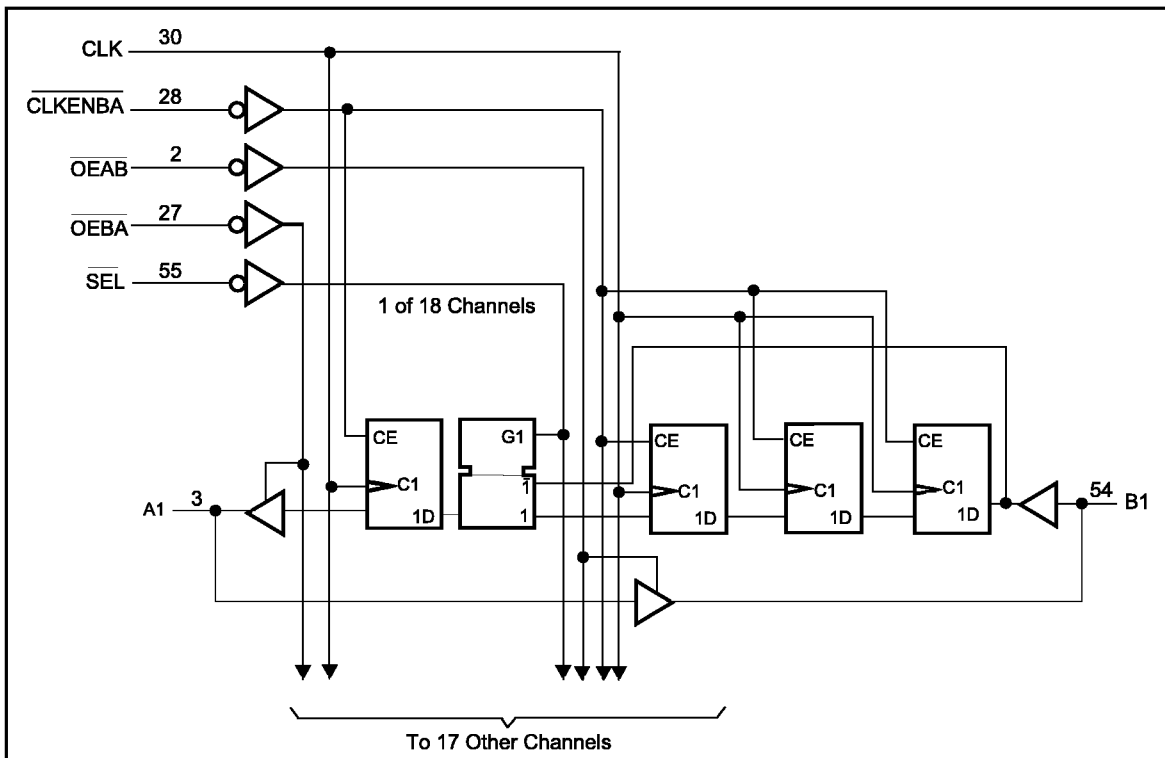
Data is stored in the internal registers on the low-to-high transition of the clock (CLK) input, provided that the appropriate $\overline{CLKENBA}$ input is low. The B-to-A data transfer is synchronized with CLK.

To reduce overshoot and undershoot, the A and B-port outputs include 26Ω series resistors.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{cc} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The PI74ALVCHR162524 has “Bus Hold” which retains the data input’s last state whenever the data input goes to high-impedance preventing “floating” inputs and eliminating the need for pullup/down resistors.

Logic Block Diagram



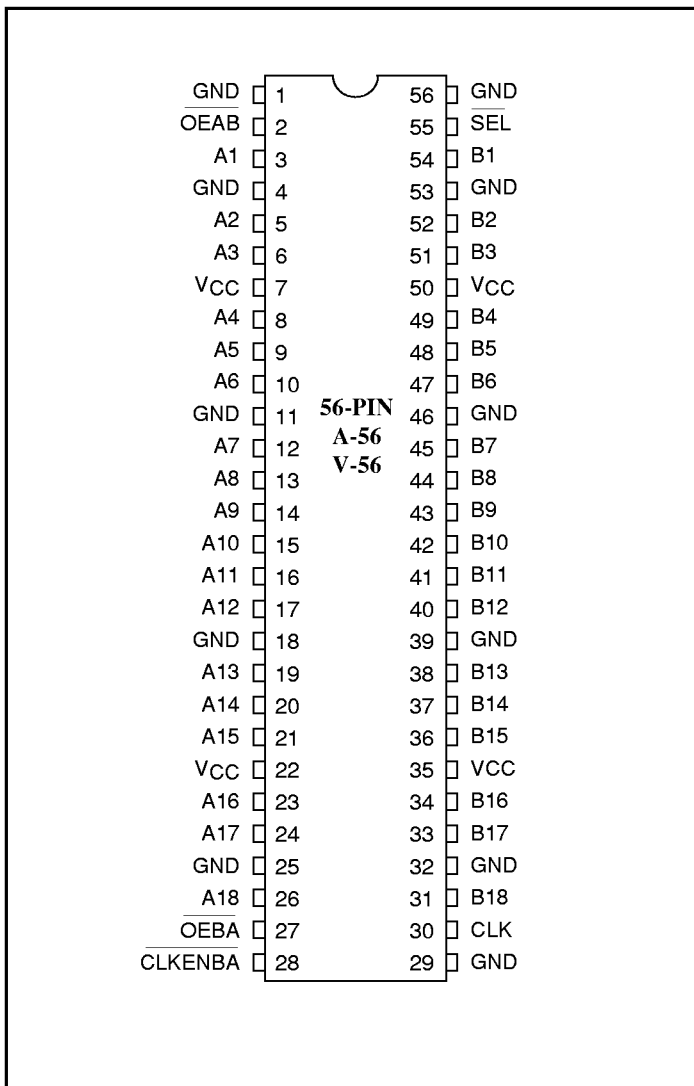
Product Pin Description

Pin Name	Description
$\overline{\text{CLKEN}}$	Clock Enable Input (Active LOW)
$\overline{\text{SEL}}$	Select (Active LOW)
CLK	Clock Input (Active HIGH)
Ax	Data I/O
Bx	Data I/O
GND	Ground
Vcc	Power

Truth Table^{(1)†} B to A Storage (OEBA = L)

Inputs				Outputs A
$\overline{\text{CLKENBA}}$	CLK	$\overline{\text{SEL}}$	B	
H	X	X	X	A0‡
L	↑	H	L	L
L	↑	H	H	H
L	↑	L	L	L§
L	↑	L	H	H§

Product Pin Configuration



Note:

- H = High Signal Level
L = Low Signal Level
Z = High Impedance
↑ = LOW-to-HIGH Transition
- ‡ Output level before the indicated steady-state input conditions were established.
- § Four positive CLK edges are needed to propagate data from B to A when $\overline{\text{SEL}}$ is low.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65°C to +150°C
Ambient Temperature with Power Applied	-40°C to +85°C
Input Voltage Range, V_{IN}	-0.5V to $V_{CC} + 0.5V$
Output Voltage Range, V_{OUT}	-0.5V to $V_{CC} + 0.5V$
DC Input Voltage	-0.5V to +5.0V
DC Output Current	100 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽¹⁾

Parameters	Description	Test Conditions	Min.	Typ.	Max.	Units
V_{CC}	Supply Voltage		2.3		3.6	V
V_{IH}	Input HIGH Voltage	$V_{CC} = 2.3V$ to $2.7V$	1.7			
		$V_{CC} = 2.7V$ to $3.6V$	2.0			
V_{IL}	Input LOW Voltage	$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 2.7V$ to $3.6V$			0.8	
V_{IN}	Input Voltage		0		V_{CC}	
V_{OUT}	Output Voltage		0		V_{CC}	
I_{OH}	High-level Output Current	$V_{CC} = 2.3V$			-12	mA
		$V_{CC} = 2.7V$			-12	
		$V_{CC} = 3.0V$			-24	
I_{OL}	Low-level Output Current	$V_{CC} = 2.3V$			12	
		$V_{CC} = 2.7V$			12	
		$V_{CC} = 3.0V$			24	
T_A	Operating Free-Air Temperature		-40		85	°C

Note:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 3.3\text{V} \pm 10\%$)

Parameters	Test Conditions		$V_{CC}^{(1)}$	Min.	Typ. ⁽²⁾	Max.	Units
V_{OH}	$I_{OH} = -100 \mu\text{A}$		Min. to Max.	$V_{CC} - 0.2$			V
	$I_{OH} = -6 \text{ mA}$	$V_{IH} = 1.7\text{V}$	2.3V	2.0			
	$I_{OH} = -12 \text{ mA}$	$V_{IH} = 1.7\text{V}$	2.3V	1.7			
		$V_{IH} = 2.0\text{V}$	2.7V	2.2			
		$V_{IH} = 2.0\text{V}$	3.0V	2.4			
$I_{OH} = -24 \text{ mA}$	$V_{IH} = 2.0\text{V}$	3.0V	2.0				
V_{OL}	$I_{OL} = 100 \mu\text{A}$		Min. to Max.			0.2	V
	$I_{OL} = 6 \text{ mA}$	$V_{IL} = 0.7\text{V}$	2.3V			0.4	
	$I_{OL} = 12 \text{ mA}$	$V_{IL} = 0.7\text{V}$	2.3V			0.7	
		$V_{IL} = 0.8\text{V}$	2.7V			0.4	
	$I_{OL} = 24 \text{ mA}$	$V_{IL} = 0.8\text{V}$	3.0V			0.55	
I_I	$V_I = V_{CC}$ or GND		3.6V			± 5	μA
I_I (Hold) ⁽³⁾	$V_I = 0.7\text{V}$		2.3V	45			
	$V_I = 1.7\text{V}$			-45			
	$V_I = 0.8\text{V}$		3.0V	75			
	$V_I = 2.0\text{V}$			-75			
	$V_I = 0$ to 3.6V		3.6V			± 500	
$I_{OZ}^{(4)}$	$V_O = V_{CC}$ or GND		3.6V			± 10	
I_{CC}	$V_I = V_{CC}$ or GND	$I_O = 0$	3.6V			40	
ΔI_{CC}	One input at $V_{CC} - 0.6\text{V}$, Other inputs at V_{CC} or GND		3V to 3.6V			750	
C_I Control Inputs	$V_I = V_{CC}$ or GND		3.3V		4		pF
C_{IO} A or B ports	$V_O = V_{CC}$ or GND		3.3V		8		pF

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient and maximum loading.
- Bus Hold maximum dynamic current required to switch the input from one state to another.
- For I/O ports, the I_{OZ} includes the input leakage current.

Timing Requirements over Operating Range

Parameters	Description	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
f _{CLOCK}	Clock frequency	0	120	0	125	0	150	MHz
t _w Pulse Duration	CLK high or low	3.2		3.2		3.0		ns
t _{SU} Setup time	B Data before CLK↑	1.5		1.2		1.1		
	SEL before CLK↑	2.7		2.4		2.1		
	CLKENBA before CLK↑	2.7		2.6		2.0		
t _H Hold time	B Data after CLK↑	1.0		0.6		1.2		
	SEL after CLK↑	0.5		0.2		0.8		
	CLKENBA after CLK↑	0.1		0.1		0.3		
Δt/Δv ⁽¹⁾	Input Transition Rise or Fall	0	10	0	10	0	10	ns/V

Note: See test circuit and waveforms.

Switching Characteristics Over Operating Range⁽¹⁾

Parameters	From (Input)	To (Output)	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Units
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
f _{MAX}			120		125		150		MHz
t _{PD}	A or B	B	1.0	4.5		4.4	1.0	4.2	ns
t _{PD}	CLK	A		5.5		5.4		4.7	
t _{EN}	OEAB or OEBA	A or B		6.1		6.1		5.1	
t _{DIS}	OEAB or OEBA	A or B		6.3		5.4		4.9	

Notes:

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.

Operating Characteristics, T_A = 25°C

Parameter		Test Conditions	V _{CC} = 2.5V ± 0.2V	V _{CC} = 3.3V ± 0.3V	Units
			Typical		
C _{PD} Power Dissipation Capacitance	Outputs Enabled	C _L = 50pF f = 10 MHz	160		pF
	Outputs Disabled				